

Application No.: 10/719209

Case No.: 57389US004

3. Semiconductor device article having two semiconductor features, such as a CMOS structure, and also having a permanently affixed shadow mask.
 4. Semiconductor device article having two semiconductor features, such as a CMOS structure, and having a removable shadow mask.
- B. Semiconductor material
1. Semiconductor material is inorganic.
 2. Semiconductor material is organic.

Applicants hereby provisionally elect number 1 (semiconductor device article having only one semiconductor feature and also having a permanently affixed shadow mask) for group A, and number 2 (semiconductor material is organic) for group B. Claims 1, 2, 3, 5, and 7 appear to be readable on a semiconductor device article having only one semiconductor feature and also having a permanently affixed shadow mask wherein the semiconductor material is organic. Applicants respectfully traverse the election requirement on the basis that the articles and devices of claims 1 – 23 should be searchable for a single application without undue burden on the PTO. Since all of the claims relate to articles comprising transistor features defined by a permanently affixed shadow mask, the searches required will be substantially the same. Applicant therefore respectfully requests reconsideration and withdrawal of the Election Requirement.

Respectfully submitted,

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